

isc Silicon NPN Power Transistor

DESCRIPTION

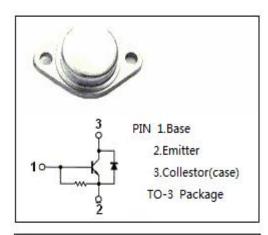
- · High Breakdown Voltage-
 - : V_{CBO}= 1500V (Min)
- High Switching Speed
- Low Collector Saturation Voltage-
 - : V_{CE(sat)}= 5.0V(Max.)@ I_C= 5A
- · Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

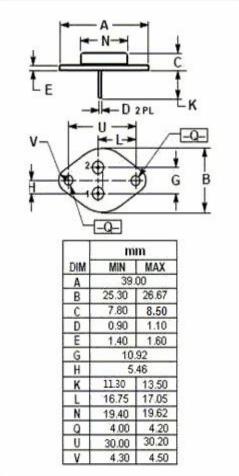
APPLICATIONS

• Designed for color TV horizontal output applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	1500	V
V _{CEO}	Collector-Emitter Voltage	600	V
V_{EBO}	Emitter-Base Voltage	V	
Ic	Collector Current- Continuous	6	А
I _E	Emitter Current- Continuous	6	А
Pc	Collector Power Dissipation @ T _C = 25 °C	50	
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-65~150	${\mathbb C}$







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2SD871

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{EBO}	Emitter-Base Breakdown Voltage	I _E = 200mA; I _C = 0	5.0			V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			10	μА
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 5V	8	12		
V _{ECF}	C-E Diode Forward Voltage	I _F = 6A		1.6	2.0	٧
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		165		pF
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V		3		MHz
t _f	Fall Time	I _C = 5A, I _{Bend} = 1A		0.5	1.0	μS

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